CMOS LSI

SANYO CM

LC7972VA, 7972VB

CMOS Operational Amplifier with Programmable Offset Correction Function

Overview

The LC7972VA and LC7972VB are dual inverting/noninverting operational amplifier ICs that are fabricated in a CMOS process. These ICs provide a programmable offset correction function and a power saving function for use when the operational amplifier is unused, both of which can be controlled from a microprocessor interface.

Features

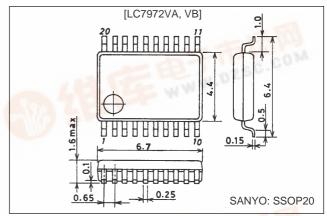
- High input impedance provided by fabrication in a CMOS process.
- Low power provided by fabrication in a CMOS process.
- One of two types of operational amplifier can be selected: inverting (operational amplifier 1) or noninverting (operational amplifier 2)
- Operating supply voltage: 4.9 to 5.2 V
- Package: SSOP20
- Operating temperature: Ta = -30 to $+70^{\circ}C$

• The following modes are supported. These are selected via port level settings.

Package Dimensions

unit: mm

3179A-SSOP20



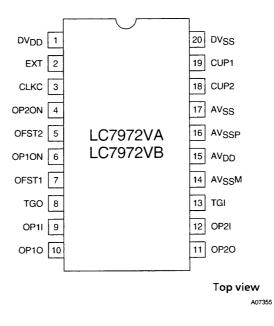
Port	Level	Function
0.0101	L	Operational amplifier 1: Operation stopped (low-power mode)
OP1ON	Н	Operational amplifier 1: Normal operation (OP2ON must be low in this mode.)
00001	L	Operational amplifier 2: Operation stopped (low-power mode)
OP2ON -	Н	Operational amplifier 2: Normal operation (OP1ON must be low in this mode.)
L		Operational amplifier 1: Offset mode (inverting input = V _{SS})
OFST1	Н	Operational amplifier 1: Operating mode (inverting input = normal input)
OFST2	L	Operational amplifier 2: Offset mode (noninverting input = V _{SS})
	Н	Operational amplifier 2: Operating mode (noninverting input = normal input)
CLKC	L	Operational amplifier power supply clock: Internal clock

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Pin Assignment

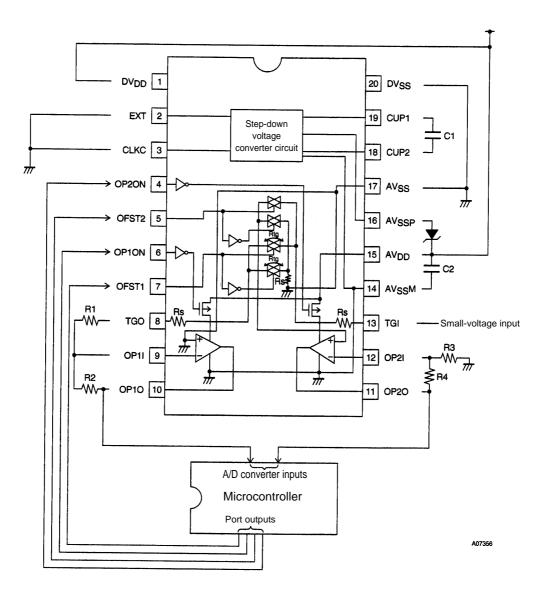


Pin Functions

Pin		-				
No.	Symbol	Function				
1	DV _{DD}	Digital system power supply. Normally connected to +5 V.				
2	EXT	Must be tied low.				
3	CLKC	Must be tied low.				
4	OP2ON	Operational amplifier 2 operation control				
5	OFST2	Operational amplifier 2 mode control				
6	OP10N	Operational amplifier 1 operation control				
7	OFST1	Operational amplifier 1 mode control				
8	TGO	Operational amplifier 1 VSS/small voltage output				
9	OP1I	Operational amplifier 1 input				
10	OP10	Operational amplifier 1 output				
11	OP2O	Operational amplifier 2 output				
12	OP2I	Operational amplifier 2 input				
13	TGI	Small voltage input common to operational amplifiers 1 and 2				
14	AV _{SS} M	Operational amplifier power supply minus voltage generation				
15	AV _{DD}	Analog system power supply. Normally connected to +5 V.				
16	AV _{SS} P	Operational amplifier power supply external Zener diode connection				
17	AV _{SS}	Analog system ground. Must be connected to 0 V.				
18	CUP2	Operational amplifier power supply external capacitor connection 2				
19	CUP1	Operational amplifier power supply external capacitor connection 1				
20	DVSS	Digital system ground. Must be connected to 0 V.				

System Block Diagram and Sample Application

A circuit that amplifies very small voltages around the V_{SS} level can be constructed by adding the peripheral circuits shown in the figure below.



Specifications

Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}$ = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max	V _{DD}	-0.3 to +7.0	V
Output voltage	Vo	OP10, OP20, TGO	-0.3 to V _{DD} +0.3	V
Input voltage	V _I 1	OP10N, OFST1, OP20N, OFST2, EXT, CLKC, CUP2, CUP1, AV_{SS}P, OP1I, OP2I, TGI $-0.3 \mbox{ to } V_{DD}+0.2 $		V
	V _l 2	AV _{SS} M	-3 to +0.3	V
Peak output current	I _{OP}	OP10, OP20, TGO	-1 to +1	mA
Average output current	I _{OA}	OP10, OP20, TGO : The current per pin	-1 to +1	mA
Allowable power dissipation	Pd max	SSOP20 : Ta = -30 to +70°C	100	mW
Operating temperature	Topr		-30 to +70	°C
Storage temperature	Tstg		-55 to +125	°C

Allowable Operating Ranges at Ta = -30 to $+70^{\circ}$ C, V_{SS} = 0 V, V_{DD} = 4.9 to 5.2 V, unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
Falameter			min	typ	max	Unit
Supply voltage	V _{DD}	V _{DD}	4.9		5.2	V
Input high-level voltage	VIH	OP1ON, OFST1, OP2ON, OFST2	$0.7 V_{DD}$		V _{DD}	V
	V _{IL} 1	OP1ON, OFST1, OP2ON, OFST2, CLKC	V _{SS}		0.3 V _{DD}	V
Input low-level voltage	V _{IL} 2	EXT	V _{SS}		0.3 V _{DD}	V
Common-mode input voltage	VIC		0		4.2	V
Voltage drop	D _V	$AV_{SS}M$: Zener diode = 5.1 V (X rank specified)		-0.2		V

Electrical Characteristics at Ta = -30 to +70 $^{\circ}$ C, V_{SS} = 0 V, V_{DD} = 4.9 to 5.2 V, unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
Farameter			min	typ	max	Unit
	I _{IH} 1	OP1ON, OFST1, OP2ON, OFST2 : $V_{IN} = V_{DD}$			1.0	μA
Input high-level current	I _{IH} 2	TGI: $V_{IN} = V_{DD}$, with the built-in TG off.			1.0	μA
Input low-level current	I _{IL} 1	OP1ON, OFST1, OP2ON, OFST2, EXT, CLKC : $V_{IN} = V_{SS}$	-1.0			μA
	I _{IL} 2	TGI: $V_{IN} = V_{SS}$, with the built-in TG off.	-1.0			μA
Output high-level voltage	V _{OH}	OP1O, OP2O : Ι _{OH} = -3 μA	V _{DD} – 0.5			V
Output low-level voltage	V _{OL}	OP10, OP2O : Ι _{OL} = 3 μA			0.5	V
Operational amplifier 1 gain-related resistance	Rtg + 2Rs	TGO, TGI	500	700	900	Ω
Operational amplifier 1 gain-related resistance difference	Rx–Ry	TGO, TGI: Offset mode: Rx = Rtg + 2Rs Operating mode: Ry = Rtg + 2Rs			80	Ω
Current drain						
Operating	IDDOP	V _{DD} ; Using the internal clock, with the operational amplifier 1 circuit operating.		700	900	μA
Standby	I _{DDST}	$V_{\mbox{\scriptsize DD}};$ Both operational amplifiers 1 and 2 stopped.		0.05	10	μA

Operational Amplifier Characteristics at Ta = $25^{\circ}C \pm 2^{\circ}C$, $V_{SS} = 0$ V, $V_{DD} = 4.9$ to 5.2 V, unless otherwise specified

Parameter	Symbol	Conditions	Ratings			- Unit
Farameter			min	typ	max	Unit
		OP1I, OP2I : LC7972VA		5	10.5	mV
Input offset voltage	V _{IO}	LC7972VB		5	15	mV
Supply voltage rejection ratio	P _{SRR}	1 kHz		60		dB
Common-mode rejection ratio	C _{MRR}			60		dB
Open-loop voltage gain	A _O			80		dB
0-dB bandwidth	f _T			90		kHz
Maximum output voltage	Vo	OP1O, OP2O : R _L ≥ 100 kΩ		V _{DD} – 0.5		V
Current drain	Icc	For the operational amplifier 1 circuit		100		μA
Settling time	T _{SET}	OP10, OP20		900		μs